

QSFP56-DD-ZR-HP

400G Coherent DWDM, QSFP56-DD DCO, ZR (High Tx Power), SMF TRANSCEIVER DUPLEX LC CONNECTOR

Product Features

- Digital Coherent Optics module, QSFP-DD form factor, Type 2A
- IEEE 400GE or 4×100GE Ethernet compliant host interface
- Coherent 400G optical interface based on OIF 400ZR implementation agreement
- High Tx output power (0dBm) enabling:
 - Unamplified DWDM links up to 40km
 - Unamplified single wavelength links up to 80km
- Dispersion limited transmission reach up to 120km
- Full C-band tunable, 75GHz or 100GHz grid
- Power dissipation < 18.5W
- Case operating temperature:
 - Commercial: 0 ~ 70°C



Product Applications

- Data center interconnect
- Metro / edge networks

I. Maximum Ratings

Exceeding the limits below may damage the transceiver module permanently.

Parameter	Conditions		Symbol	Min.	Typ.	Max.	Unit	Notes
DC Supply Voltage			V _{CC}	-0.3		3.6	V	
Low Speed I/O Voltages				-0.3		3.6	V	
Storage Temperature			T _s	-40		85	°C	
Case Operating Temperature			T _{op}	-5		75	°C	
Relative Humidity	Non-condensing		RH	5		95	%	
Rx Input Power			P _{RX,IN}			18	dBm	
ESD damage threshold	HBM	DC pins			2000		V	
		RF pins			1000			

II. Operating Specifications

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	Notes
Storage Temperature		T _s	-40		85	°C	
Case Operating Temperature		T _{op}	0		70	°C	
Relative Humidity	Non-condensing	RH	5		85	%	

III. Host and Line Interface Modules

A. Host Interface Modules

Host Interface ID	Host Interface Description	Modulation	Forward Error Correction Code	Nominal Symbol Rate (GBd)	Supported Line Interface IDs
17	400GAUI-8	PAM4	RS(544,514)	26.5625	62, 63
13	4 × 100GAUI-2	PAM4	RS(544,514)	26.5625	62, 63

B. Line Interface Modules

Line Interface ID	Line Interface Description	Modulation	Forward Error Correction Code	Nominal Symbol Rate (GBd)	Spectral Shaping
62	400ZR, DWDM, Amplified	16QAM	C-FEC	59.8438	None
63	400ZR, Single Wavelength, Unamplified	16QAM	C-FEC	59.8438	None

IV. Electrical Characteristics

A. Power & Low Speed I/O

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	Notes
Power Supply - General							
Power supply voltages	Including ripple, droop and noise below 100kHz		3.135	3.300	3.465	V	
Host RMS noise output	40Hz - 10MHz				25	mV	
Module RMS noise output	10Hz - 10MHz				30	mV	
Module supply noise tolerance	10Hz - 10MHz, peak-to-peak	PSNR _{mod}			66	mV	
Module inrush	Instantaneous peak duration	T _{ip}			50	μs	
	Initialization time	T _{init}			500	ms	

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Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	Notes
Power Supply - Low Power Mode							
Power dissipation		P _{lp}			1.5	W	
Power supply current	Instantaneous peak current	I _{CC,ip,lp}			600	mA	
	Sustained peak current	I _{CC,sp,lp}			495		
	Steady state current	I _{CC,lp}			475		
Power Supply - High Power Mode - 400GE client							
Power dissipation		P _{lp}			18.2	W	
Power supply current	Instantaneous peak current	I _{CC,ip,hp}			7.4	A	
	Sustained peak current	I _{CC,sp,hp}			6.2		
	Steady state current	I _{CC,hp}			6.0		
Power Supply - High Power Mode – 4x100GE client							
Power dissipation		P _{lp}			19.5	W	
Power supply current	Instantaneous peak current	I _{CC,ip,hp}			7.8	A	
	Sustained peak current	I _{CC,sp,hp}			6.5		
	Steady state current	I _{CC,hp}			6.3		
Low speed I/O							
Output voltage, SCL and SDA	Output Low	V _{OL}	0.0		0.4	V	
	Output High	V _{OH}	V _{CC} -0.5		V _{CC} +0.3		
Input voltage, SCL and SDA	Input Low	V _{IL}	-0.3		0.3xV _{CC}	V	
	Input High	V _{IH}	0.7xV _{CC}		V _{CC} +0.5		
Capacitance for SCL and SDA I/O signal		C _i			14	pF	
Total bus capacitive load for SCL and SDA	400kHz clock rate, 3.0kΩ pull-up, max.	C _b			100	pF	1
	400kHz clock rate, 1.6kΩ pull-up, max.				200		
Input voltage / current, InitMode, ResetL and ModSelL	Input voltage, Low	V _{IL}	-0.3		0.8	V	
	Input voltage, High	V _{IH}	2.0		V _{CC} +0.3		
	Input current, 0V < V _{in} < V _{CC}	I _{in}			360	μA	
Output voltage, IntL	Output low, I _{OL} = 2mA	V _{OL}	0.0		0.4	V	
	Output high, 10kΩ pull-up resistor to host V _{CC}	V _{OH}	V _{CC} -0.5		V _{CC} +0.3		
Output voltage, ModPrsL	Output low, I _{OL} = 2mA	V _{OL}	0.0		0.4	V	2
	Output high	V _{OH}					

Notes:

- For 1000kHz clock rate refer to Figure 6 in QSFP-DD MSA “QSFP-DD/QSFP-DD800/QSFP112 Hardware Specification for QSFP Double Density 8x and QSFP 4x Pluggable Transceivers” Revision 6.3 (July 26, 2022).
- ModPrsL can be implemented as a short-circuit to GND on the module.

B. High Speed Data I/O

Parameter	Symbol	Min.	Typ.	Max.	Unit	Notes
Transmitter (module input) - 400GAUI-8, 100GAUI-2						
Signaling rate per lane		Per IEEE Std 802.3 [IEEE Computer Society “IEEE Standard for Ethernet”, IEEE Std. 802.3TM-2022], Annex 120E, Table 120E–7			GBd	
Differential pk-pk input voltage tolerance					mV	
Differential input return loss					dB	
Differential to common mode input return loss					dB	
Differential termination mismatch					%	
Module stressed input test						
Single-ended voltage tolerance range					V	
DC common mode voltage					mV	
Receiver (module output) - 400GAUI-8, 100GAUI-2						
Signaling rate per lane		Per IEEE Std 802.3 [IEEE Computer Society “IEEE Standard for Ethernet”, IEEE Std. 802.3TM-2022], Annex 120E, Table 120E–3			GBd	
AC common-mode output voltage					mV	
Differential peak-to-peak output voltage					mV	
Near-end ESMW					UI	
Near-end eye height, differential					mV	
Far-end ESMW					UI	
Far-end eye height, differential					mV	
Far-end pre-cursor ISI ratio					%	
Differential output return loss					dB	
Common to differential mode conversion return loss					dB	
Differential termination mismatch					%	
Transition time					ps	
DC common mode voltage					mV	

V. Optical Characteristics

A. General

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	Notes
Symbol rate		R_{baud}		59.84		GBd	
Modulation format			16QAM				
Channel frequency range	100GHz grid	V_C	191.400		196.100	THz	
	75GHz grid		191.375		196.100		
Channel spacing	100GHz grid	ΔV_C		100		GHz	
	75GHz grid			75			
Frequency accuracy		δV_C	-1.5		1.5	GHz	
Laser intrinsic linewidth	Calculated based on FM noise power spectral density (PSD) measurement	LW			300	KHz	
Side-mode suppression ratio	No modulation	SMSR	40			dB	
Relative intensity noise	Peak over 0.2GHz < f < 10GHz	RIN			-140	dB/Hz	
	Average over 0.2GHz < f < 10GHz				-145		

B. Transmitter

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	Notes
Tx output power configurable range		$P_{\text{Tx,out}}$	-6	0	1	dBm	1
Tx output power adjustment resolution					0.1	dB	
Tx output power tolerance		$\delta P_{\text{Tx,out}}$	-1.0		1.0	dB	2
Tx output power monitor range		$P_{\text{Tx,m}}$	-8		2	dBm	
Tx output power monitor accuracy		$\delta P_{\text{Tx,m}}$	-1.0		1.0	dB	3
Tx output power during tuning or when Tx disabled		$P_{\text{Tx,dark}}$			-35	dBm	
Tx output power imbalance between X- and Y-polarizations		$\Delta P_{X/Y}$			1.5	dB	
Tx XY skew					5.0	ps	
Tx IQ offset					-26	dB	
Tx IQ imbalance					1.0	dB	
Tx quadrature error			-5.0		5.0	°	
Tx IQ skew					0.75	ps	
Tx in-band optical signal to noise ratio	Under modulation, $ \Delta f < 150 \text{ GHz}$	OSNR_{in}	40			dB/0.1nm	

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Parameter	Conditions		Symbol	Min.	Typ.	Max.	Unit	Notes
Tx out-of-band optical signal to noise ratio	Under modulation, $ \Delta f > 150$ GHz, excluding side mode peaks	Max PTx,out	OSNR _{out}	40			dB/ 0.1nm	
		Min PTx,out		35				
Tx reflectance						-27	dB	

Notes:

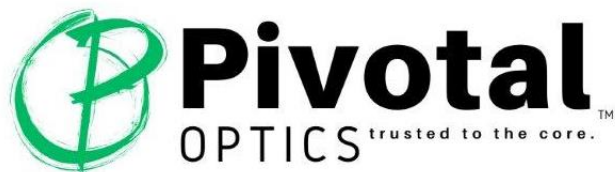
1. Range of target Tx output power values for which other Tx specifications can be maintained.
2. Deviation from target value under closed loop control, over all operating conditions and life.
3. Tx optical output power monitor reading relative to actual Tx output power.

C. Receiver

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	Notes
Rx signal input power (amplified)	Full Rx OSNR tolerance	P _{Rx,sig}	-12		0	dBm	
	Extended range		-15		1		1
Rx OSNR tolerance			26			dB/0.1nm	
CD tolerance	OSNR penalty < 0.5dB		-2.4		2.4	ns/nm	2
PMD tolerance	OSNR penalty < 0.5dB				10	ps	2
Tolerance to change in SOP	OSNR penalty < 0.5dB				60	krad/s	2
Polarization dependent loss OSNR penalty	1dB PDL				0.5	dB	2
	2dB PDL				1.0		
	4dB PDL				2.0		
Rx signal input power transient amplitude	Peak excursion from steady state (within Rx signal input power range)		-3		3	dB	
Rx signal input power transient rise/fall time			0.1			ms	
Rx signal input power (unamplified)	OSNR > 35dB/0.1nm		-22		0	dBm	
Rx signal input power monitor range		P _{Rx,m(s)}	-22		1	dBm	
Rx signal input power monitor accuracy		δP _{Rx,m(s)}	-2.0		2.0	dB	
Rx total input power monitor range		P _{Rx,m(t)}	-22		3	dBm	
Rx total input power monitor accuracy	-22dBm to -18dBm	δP _{Rx,m(t)}	-2.0		2.0	dB	
	-18dBm to +3dBm		-1.5		1.5		
Rx reflectance					-27	dB	

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Notes:

1. Rx signal input power range over which performance can be guaranteed with <1dB OSNR penalty relative to Rx OSNR tolerance limit.
2. Rx OSNR penalty is specified for Rx signal input powers < 0dBm.

VI. Module Timing Characteristics

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	Notes
Optical							
Tx turn on time	Warm Start				100	ms	
	Cold Start				150	s	
Rx acquisition time	Warm Start				30	ms	
	Cold Start				150	s	
Tx/Rx channel tuning time					30	s	

VII. Ordering Information

Pivotal Part Number	Description
QSFP56-DD-ZR-HP	QSFP56-DD DCO, 400G Coherent DWDM, High Tx Power ZR SMF, LC DDM, C-Temp

Notes:

1. Please contact sales for specific OEM Platform part numbers to fit your network.

Warranty

<https://pivotaloptics.com/warranty/>

Disclaimer

External physical characteristics are subject to variation. This may include, but is not limited to, external case designs, pull tab colors and/or shapes, removal latch styles or colors, and label sizes and placement. These variations do not affect the function or characteristics of the transceivers.